

TSM250N02CX

20V N-Channel Power MOSFET



Pin Definition:

1. Gate
2. Source
3. Drain

Note:

MSL 1 (Moisture Sensitivity Level) per J-STD-020

Key Parameter Performance

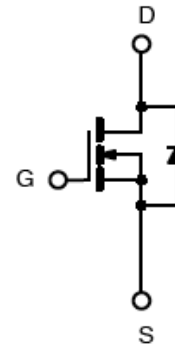
Parameter	Value	Unit
V_{DS}	20	V
$R_{DS(on)}$ (max)	$V_{GS} = 4.5V$	25
	$V_{GS} = 2.5V$	35
	$V_{GS} = 1.8V$	55
Q_g	7.7	nC

Ordering Information

Ordering code	Package	Packing
TSM250N02CX RFG	SOT-23	3kpcs / 7" Reel

- Note: Halogen-free according to IEC 61249-2-21 definition

Block Diagram



N-Channel MOSFET

Absolute Maximum Ratings ($T_C = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 10	V
Continuous Drain Current	I_D	$T_C = 25^\circ C$	5.8
		$T_C = 100^\circ C$	3.7
Pulsed Drain Current ^(Note 1)	I_{DM}	23.2	A
Power Dissipation @ $T_C = 25^\circ C$	P_D	1.56	W
Operating Junction Temperature	T_J	150	$^\circ C$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ C$

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Ambient	$R_{\theta JA}$	80	$^\circ C/W$

Electrical Specifications ($T_C = 25^\circ\text{C}$ unless otherwise noted)

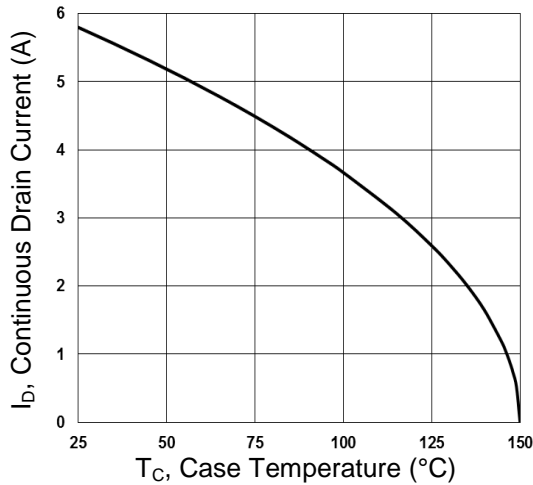
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	BV_{DSS}	20	--	--	V
Drain-Source On-State Resistance	$V_{GS} = 4.5\text{V}, I_D = 4\text{A}$	$R_{DS(on)}$	--	20	25	m Ω
	$V_{GS} = 2.5\text{V}, I_D = 3\text{A}$		--	27	35	
	$V_{GS} = 1.8\text{V}, I_D = 2\text{A}$		--	39	55	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	$V_{GS(TH)}$	0.4	0.6	0.8	V
Zero Gate Voltage Drain Current	$V_{DS} = 16\text{V}, V_{GS} = 0\text{V}$	I_{DSS}	--	--	1	μA
	$V_{DS} = 16\text{V}, T_J = 85^\circ\text{C}$		--	--	10	
Gate Body Leakage	$V_{GS} = \pm 10\text{V}, V_{DS} = 0\text{V}$	I_{GSS}	--	--	± 100	nA
Forward Transconductance ^(Note 2)	$V_{DS} = 10\text{V}, I_S = 3\text{A}$	g_{fs}	--	6.5	--	S
Dynamic						
Total Gate Charge ^(Note 2,3)	$V_{DS} = 10\text{V}, I_D = 4\text{A},$ $V_{GS} = 4.5\text{V}$	Q_g	--	7.7	--	nC
Gate-Source Charge ^(Note 2,3)		Q_{gs}	--	0.9	--	
Gate-Drain Charge ^(Note 2,3)		Q_{gd}	--	2.4	--	
Input Capacitance	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V},$ $f = 1.0\text{MHz}$	C_{iss}	--	535	--	pF
Output Capacitance		C_{oss}	--	60	--	
Reverse Transfer Capacitance		C_{rss}	--	34	--	
Switching						
Turn-On Delay Time ^(Note 2,3)	$V_{DD} = 10\text{V}, I_D = 1\text{A},$ $V_{GS} = 4.5\text{V}, R_G = 25\Omega$	$t_{d(on)}$	--	4.1	--	ns
Turn-On Rise Time ^(Note 2,3)		t_r	--	11.6	--	
Turn-Off Delay Time ^(Note 2,3)		$t_{d(off)}$	--	23.9	--	
Turn-Off Fall Time ^(Note 2,3)		t_f	--	7.6	--	
Source-Drain Diode Ratings and Characteristic						
Maximum Continuous Drain-Source Diode Forward Current	Integral reverse diode in the MOSFET	I_S	--	--	5.8	A
Maximum Pulse Drain-Source Diode Forward Current		I_{SM}	--	--	23.2	A
Diode-Source Forward Voltage	$V_{GS} = 0\text{V}, I_S = 1\text{A}$	V_{SD}	--	--	1	V

Note:

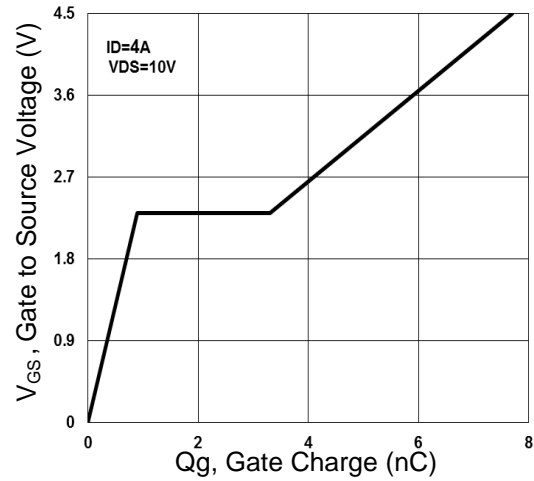
1. Pulse width limited by safe operating area
2. Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
3. Switching time is essentially independent of operating temperature.

Electrical Characteristics Curve

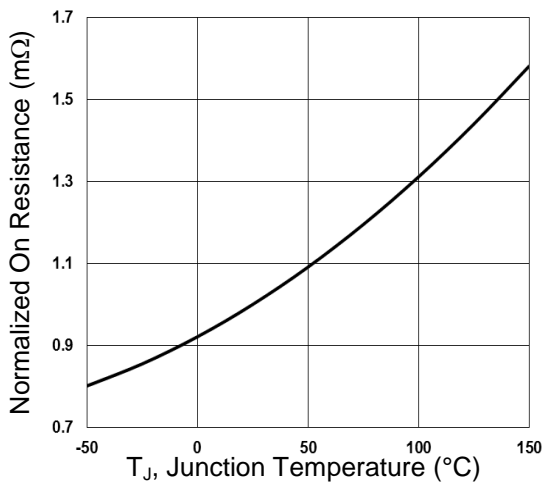
Continuous Drain Current vs. T_c



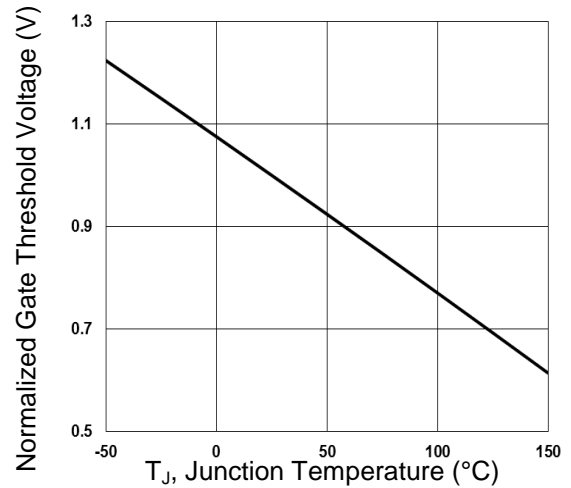
Gate Charge



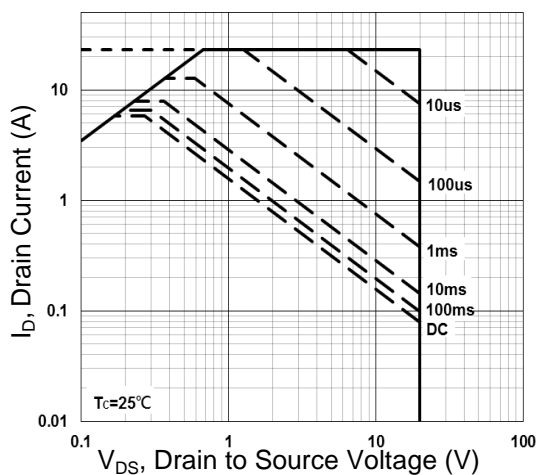
On-Resistance vs. Junction Temperature



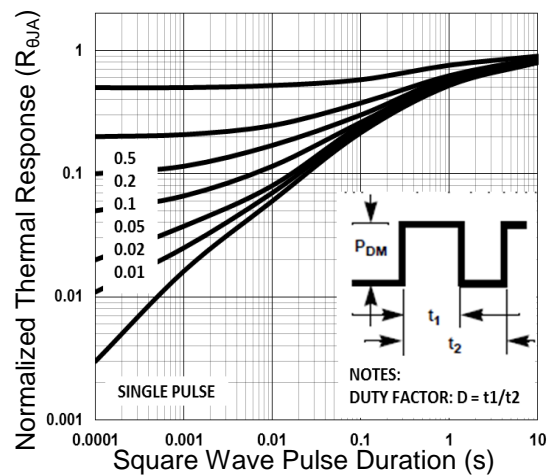
Threshold Voltage vs. Junction Temperature



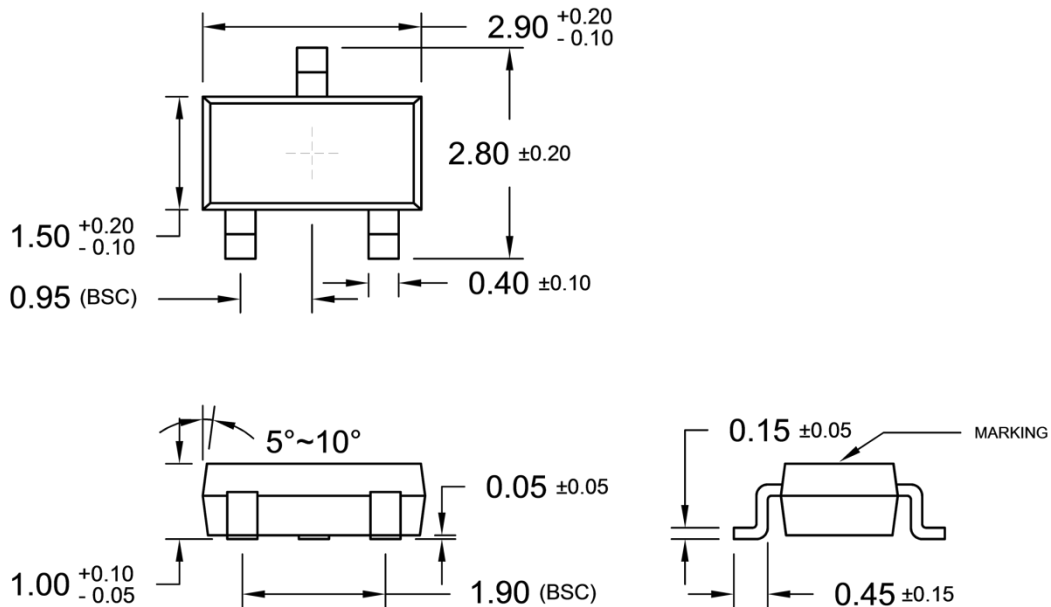
Maximum Safe Operating Area



Normalized Thermal Transient Impedance Curve

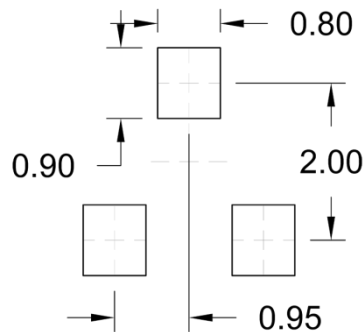


SOT-23 Mechanical Drawing

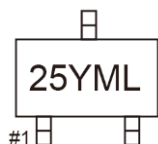


Unit: Millimeters

SUGGESTED PAD LAYOUT (Unit: Millimeters)



Marking Diagram



- 25** = Device Code
- Y** = Year Code
- M** = Month Code for Halogen Free Product
(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)
- L** = Lot Code

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